TOSHIBA CMOS Digital Integrated Circuit   Silicon Monolithic

TC74HC4094AP,TC74HC4094AF,TC74HC4094AFN

8-Bit Shift and Store Register (3-state)

The TC74HC4094A is a high speed CMOS 8-BIT SHIFT AND STROBE REGISTER fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.
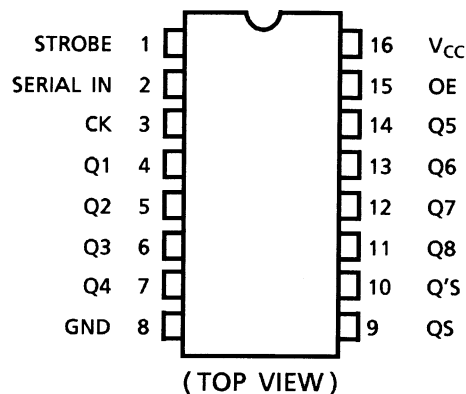
It consists of an 8-bit shift register and an 8-bit latch with 3-state output buffers. Data is shifted serially though the shift register on the positive going transition of the CK input. The output of the last stage (Qs) can be used to cascade several devices. Data on the Qs output is transferred to a second output (Q's) on the following negative transition of the CK input. The data in each stage of the shift register is provided to a corresponding latch, on the negative going transition of the STROBE input. When STROBE is held high, data propagates through the latch to a 3-state output buffer. This buffer is enabled when OUTPUT ENABLE input is set high.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.
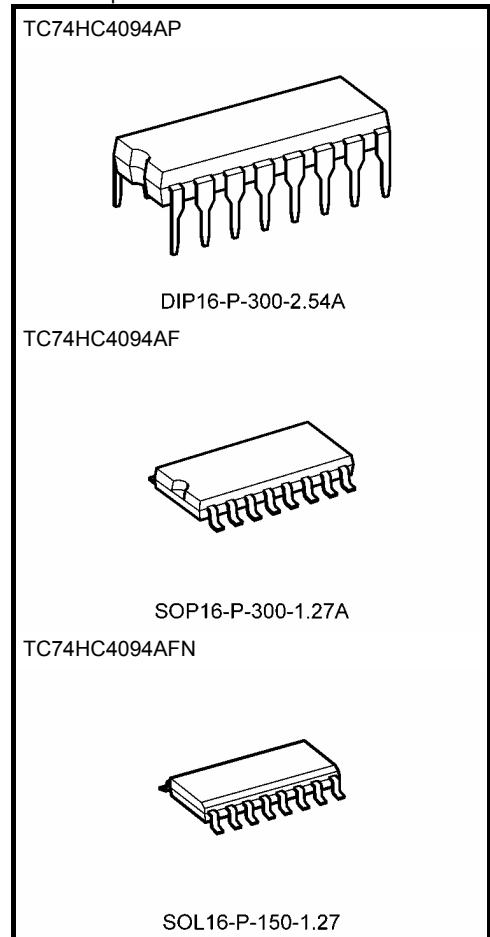
Features

- High speed: f_{max} = 73 MHz (typ.) at V_{CC} = 5 V
- Low power dissipation: I_{CC} = 4 μA (max) at Ta = 25°C
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)
- Output drive capability: 10 LSTTL loads
- Symmetrical output impedance: $|I_{OH}|$ = I_{OL} = 4 mA (min)
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: V_{CC} (opr) = 2 to 6 V
- Pin and function compatible with 4094B

Pin Assignment

(TOP VIEW)

STROBE	1	16	V_{CC}
SERIAL IN	2	15	OE
CK	3	14	Q5
Q1	4	13	Q6
Q2	5	12	Q7
Q3	6	11	Q8
Q4	7	10	Q'S
GND	8	9	QS

Note: xxxFN (JEDEC SOP) is not available in Japan.

TC74HC4094AP

DIP16-P-300-2.54A

TC74HC4094AF

SOP16-P-300-1.27A

TC74HC4094AFN

SOL16-P-150-1.27

Weight
DIP16-P-300-2.54A   : 1.00 g (typ.)
SOP16-P-300-1.27A   : 0.18 g (typ.)
SOL16-P-150-1.27   : 0.13 g (typ.)
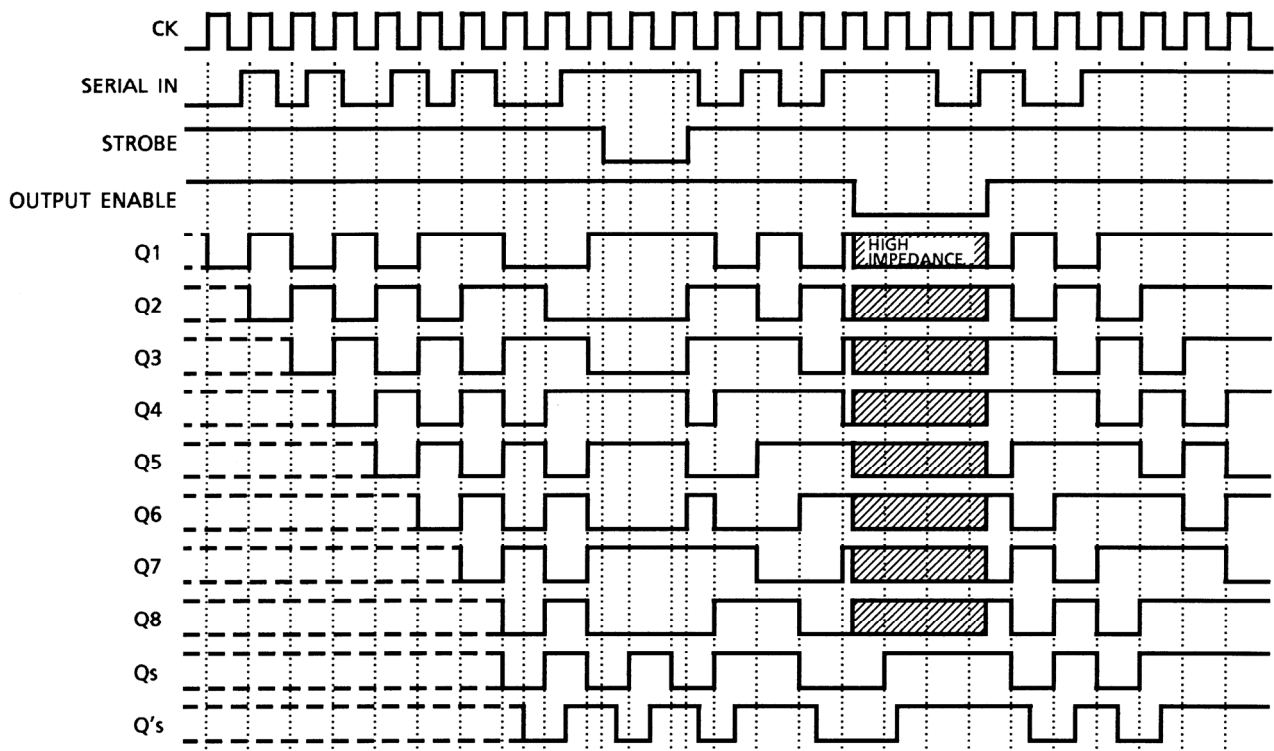
IEC Logic Symbol
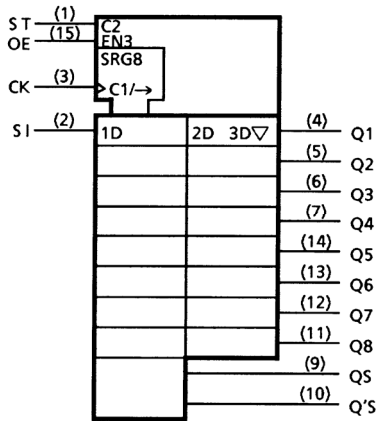
Truth Table

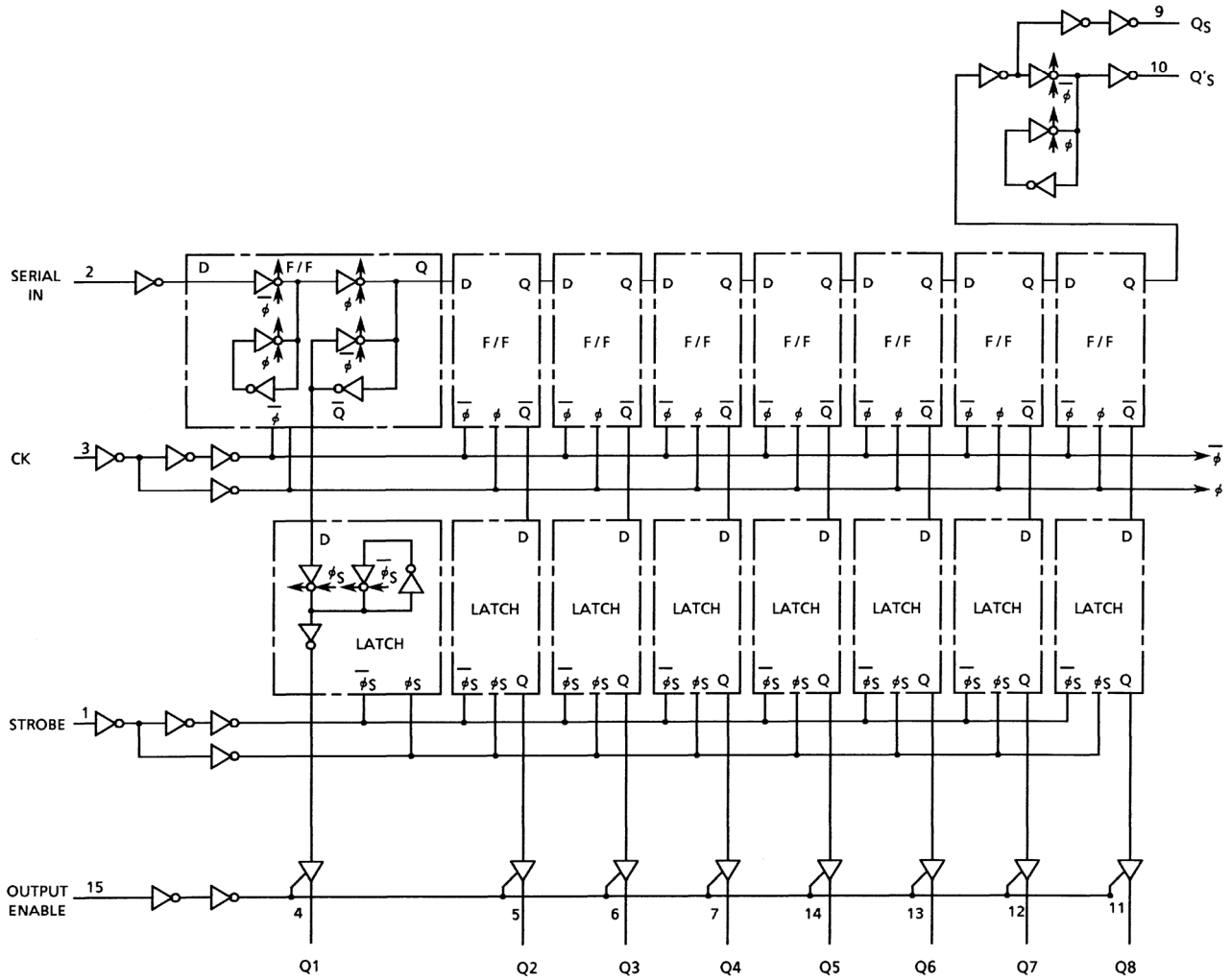| CK	OE	ST	SI	Para. Out		Seri. Out	
				Q1	Qn	Qs	Q's
↑	H	H	L	L	Qn − 1	Q7	NC
↑	H	H	H	H	Qn − 1	Q7	NC
↑	H	L	*	NC	NC	Q7	NC
↑	L	*	*	Z	Z	Q7	NC
↓	H	*	*	NC	NC	NC	Qs
↓	L	*	*	Z	Z	NC	Qs

X: Don't care

NC: No change

Z: High impedance

Timing Chart

System Diagram

Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	−0.5 to 7	V
DC input voltage	V_{IN}	−0.5 to V_{CC} + 0.5	V
DC output voltage	V_{OUT}	−0.5 to V_{CC} + 0.5	V
Input diode current	I_{IK}	±20	mA
Output diode current	I_{OK}	±20	mA
DC output current	I_{OUT}	±25	mA
DC V_{CC}/ground current	I_{CC}	±50	mA
Power dissipation	P_D	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T_{stg}	−65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = −40 to 65°C. From Ta = 65 to 85°C a derating factor of −10 mW/°C shall be applied until 300 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2 to 6	V
Input voltage	V_{IN}	0 to V_{CC}	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Operating temperature	T_{opr}	−40 to 85	°C
Input rise and fall time	t_r, t_f	0 to 1000 (V_{CC} = 2.0 V) 0 to 500 (V_{CC} = 4.5 V) 0 to 400 (V_{CC} = 6.0 V)	ns

Note: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		V_{CC} (V)	Ta = 25°C			Ta = −40 to 85°C		Unit
					Min	Typ.	Max	Min	Max	
High-level input voltage	V_{IH}	—		2.0	1.50	—	—	1.50	—	V
				4.5	3.15	—	—	3.15	—	
				6.0	4.20	—	—	4.20	—	
Low-level input voltage	V_{IL}	—		2.0	—	—	0.50	—	0.50	V
				4.5	—	—	1.35	—	1.35	
				6.0	—	—	1.80	—	1.80	
High-level output voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −20 μA	2.0	1.9	2.0	—	1.9	—	V
				4.5	4.4	4.5	—	4.4	—	
				6.0	5.9	6.0	—	5.9	—	
			I_{OH} = −4 mA	4.5	4.18	4.31	—	4.13	—	
			I_{OH} = −5.2 mA	6.0	5.68	5.80	—	5.63	—	
Low-level output voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 20 μA	2.0	—	0.0	0.1	—	0.1	V
				4.5	—	0.0	0.1	—	0.1	
				6.0	—	0.0	0.1	—	0.1	
			I_{OL} = 4 mA	4.5	—	0.17	0.26	—	0.33	
			I_{OL} = 5.2 mA	6.0	—	0.18	0.26	—	0.33	
3-state output off-state current	I_{OZ}	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND		6.0	—	—	±0.5	—	±5.0	μA
Input leakage current	I_{IN}	V_{IN} = V_{CC} or GND		6.0	—	—	±0.1	—	±1.0	μA
Quiescent supply current	I_{CC}	V_{IN} = V_{CC} or GND		6.0	—	—	4.0	—	40.0	μA

Timing Requirements (input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = −40 to 85°C	Unit
			V_{CC} (V)	Typ.	Limit	Limit	
Minimum pulse width (CK)	$t_{W (H)}$ $t_{W (L)}$	—	2.0	—	75	95	ns
			4.5	—	15	19	
			6.0	—	13	16	
Minimum pulse width (STROBE)	$t_{W (H)}$	—	2.0	—	75	95	ns
			4.5	—	15	19	
			6.0	—	13	16	
Minimum set-up time (SERIAL)	t_s	—	2.0	—	75	95	ns
			4.5	—	15	19	
			6.0	—	13	16	
Minimum set-up time (STROBE)	t_s	—	2.0	—	100	125	ns
			4.5	—	20	25	
			6.0	—	17	21	
Minimum hold time (SERIAL)	t_h	—	2.0	—	0	0	ns
			4.5	—	0	0	
			6.0	—	0	0	
Minimum hold time (STROBE)	t_h	—	2.0	—	0	0	ns
			4.5	—	0	0	
			6.0	—	0	0	
Clock frequency	f	—	2.0	—	6	5	MHz
			4.5	—	30	24	
			6.0	—	35	28	

AC Characteristics ($C_L = 15$ pF, $V_{CC} = 5$ V, Ta = 25°C, input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Output transition time	t_{TLH} t_{THL}	—	—	4	8	ns
Propagation delay time (CK-Qn)	t_{pLH} t_{pHL}	—	—	22	35	ns
Propagation delay time (CK-QS, Q'S)	t_{pLH} t_{pHL}	—	—	16	25	ns
Propagation delay time (STROBE-Qn)	t_{pLH} t_{pHL}	—	—	16	27	ns
3-state output enable time	t_{pZL} t_{pZH}	$R_L = 1$ kΩ	—	13	25	ns
Maximum clock frequency	f_{max}	—	33	73	—	MHz

AC Characteristics (C$_L$ = 50 pF, input: t$_r$ = t$_f$ = 6 ns)

Characteristics	Symbol	Test Condition	V$_{CC}$ (V)	Ta = 25°C Min	Ta = 25°C Typ.	Ta = 25°C Max	Ta = −40 to 85°C Min	Ta = −40 to 85°C Max	Unit
Output transition time	t$_{TLH}$ t$_{THL}$	—	2.0	—	30	75	—	95	ns
			4.5	—	8	15	—	19	
			6.0	—	7	13	—	16	
Propagation delay time (CK-Qn)	t$_{pLH}$ t$_{pHL}$	—	2.0	—	92	200	—	250	ns
			4.5	—	26	40	—	50	
			6.0	—	20	34	—	43	
Propagation delay time (CK-QS, Q'S)	t$_{pLH}$ t$_{pHL}$	—	2.0	—	65	150	—	190	ns
			4.5	—	19	30	—	38	
			6.0	—	15	26	—	32	
Propagation delay time (STROBE-Qn)	t$_{pLH}$ t$_{pHL}$	—	2.0	—	75	160	—	200	ns
			4.5	—	20	32	—	40	
			6.0	—	16	27	—	34	
3-state output enable time	t$_{pZL}$ t$_{pZH}$	R$_L$ = 1 kΩ	2.0	—	58	150	—	190	ns
			4.5	—	16	30	—	38	
			6.0	—	13	26	—	32	
3-state output disable time	t$_{pLZ}$ t$_{pHZ}$	R$_L$ = 1 kΩ	2.0	—	35	150	—	190	ns
			4.5	—	16	30	—	38	
			6.0	—	13	26	—	32	
Maximum clock frequency	f$_{max}$	—	2.0	6	16	—	5	—	MHz
			4.5	30	66	—	24	—	
			6.0	35	80	—	28	—	
Input capacitance	C$_{IN}$	—		—	5	10	—	10	pF
Bus input capacitance	C$_{OUT}$	—		—	10	—	—	—	pF
Power dissipation capacitance	C$_{PD}$ (Note)	—		—	140	—	—	—	pF

Note: C$_{PD}$ is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC} \text{ (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

Package Dimensions

DIP16-P-300-2.54A   Unit : mm
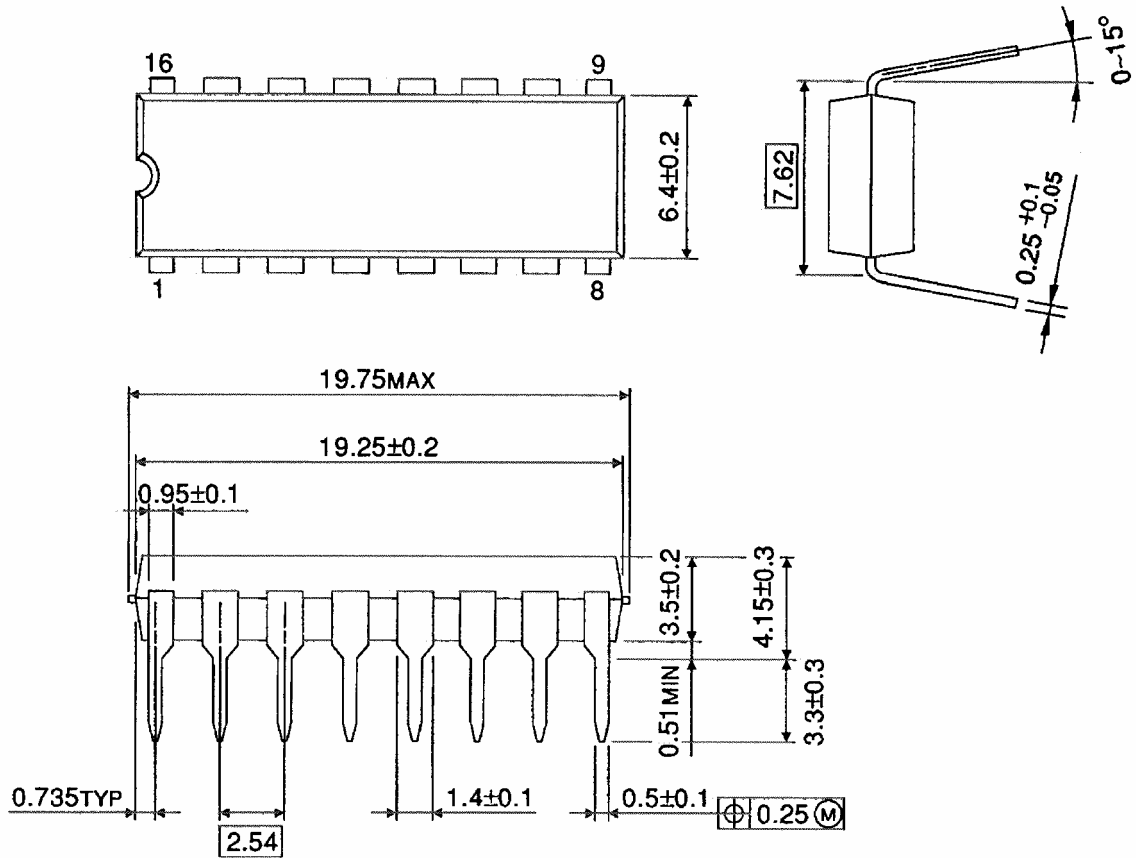
Weight: 1.00 g (typ.)

Package Dimensions

SOP16-P-300-1.27A   Unit: mm

16   9

5.3 ± 0.2   7.8 ± 0.3

1   8

0.705TYP   1.27   0.43 +0.07 −0.04   ⊕ 0.25 Ⓜ

10.8MAX

10.3 ± 0.2

1.9MAX

▱ 0.1

0.1 +0.1 −0.05   1.5 ± 0.2

0.15 +0.075 −0.035   0 ~ 10°   0.25

0.8 ± 0.2
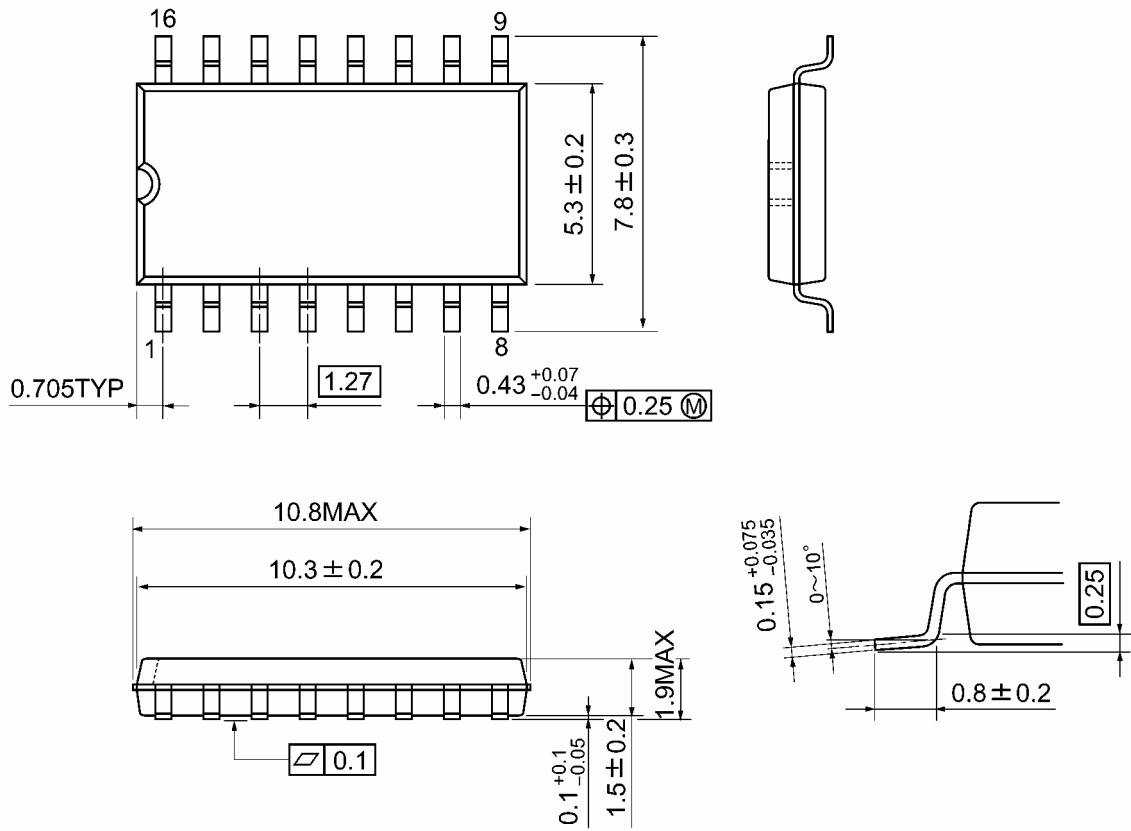
Weight: 0.18 g (typ.)

Package Dimensions (Note)

SOL16-P-150-1.27   Unit : mm
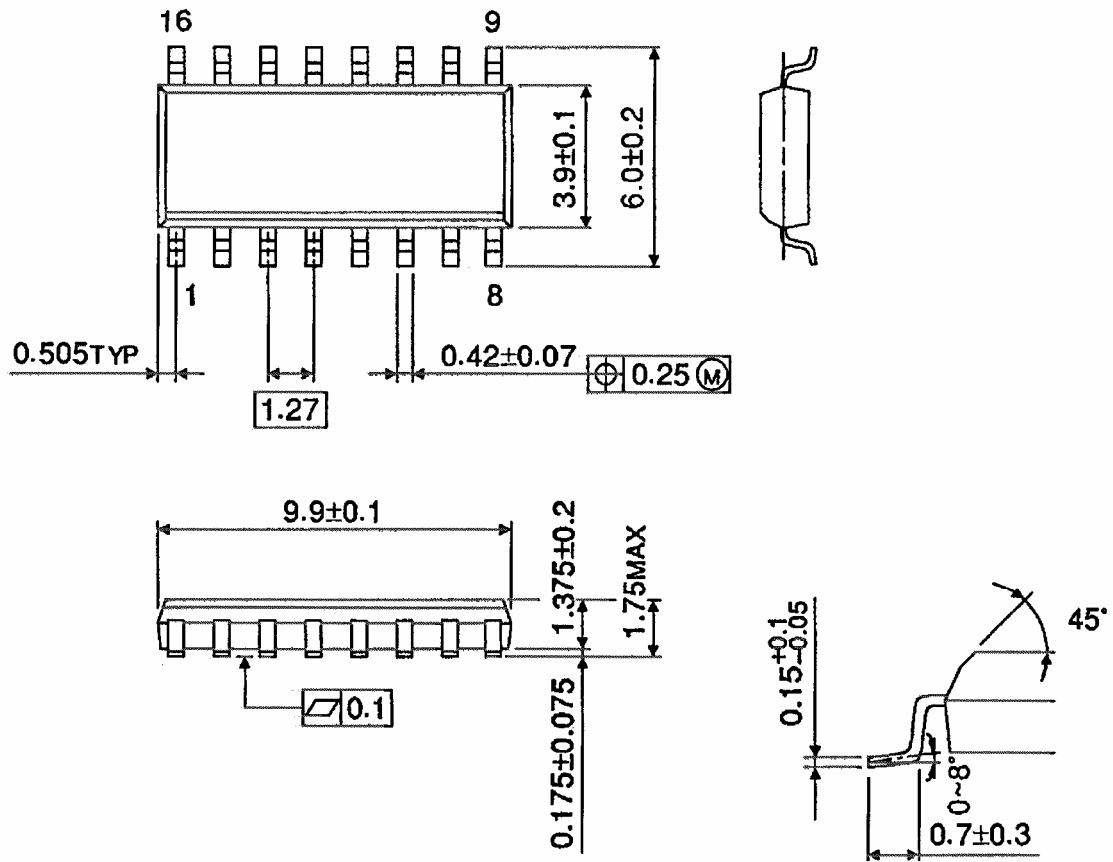
Note: This package is not available in Japan.

Weight: 0.13 g (typ.)

RESTRICTIONS ON PRODUCT USE